

# **LEAD-FREE / RoHS-COMPLIANT**

# **HIGH POWER BIAS TEE**

**BTN1-0018** 

The BTN1-0018 is constructed using a custom-made, resonance-free conical inductor to achieve extremely broadband performance. By minimizing the overall inductor size and using proprietary packaging techniques, the BTN1-0018 is a superior option in terms of performance, reliability and ease-of-use when compared to cumbersome user-designed bias tees employing off-the-shelf conical inductors. The extremely low cutoff and resonance free operation makes the BTN1-0018 suitable for biasing amplifiers, lasers, and modulators driven with high frequency data patterns.



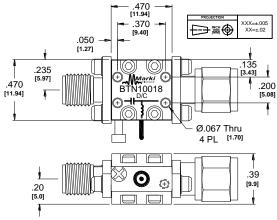
#### **Features**

- Broadband: 500 kHz to 18 GHz
- Low Insertion Loss
- High Power
- Non-Resonant
- Compact Size

**Electrical Specifications -** Specifications guaranteed from -55 to +100 $^{\circ}$ C, measured in a 50 $\Omega$  system.

Parameter	Frequency Range	Min	Тур	Max
Incortion Loca (dD)	4 MHz-18 GHz		0.7	1.5
Insertion Loss (dB)	500 kHz-4 MHz		2	
DC Port Isolation (dB)	500 kHz -1 GHz		50	
	1-18 GHz		30	
Return Loss (dB)	500 kH = 40 CH =		16	
RF Power (W)	500 kHz-18 GHz			10
DC Current (A)				1
DC Voltage (V)				50
DC Resistance (Ω)			0.5	
Inductance (uH)			22	
Capacitance (nF)			100	
Weight (g)			10	
Risetime /Falltime (ps) <sup>1</sup>			10	

<sup>&</sup>lt;sup>1</sup>Specified as 90%/10%. Calculated from  $\tau_{bt}^2 = (\tau_{out}^2 - \tau_{in}^2)$ 



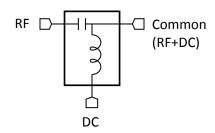


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### **Schematic**



# **Application Examples**

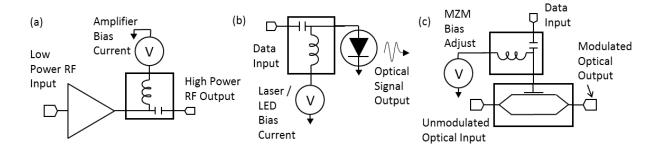


Fig. 1. Example Schematics of a) Broadband Microwave Amplifier Biasing, b) Laser/LED Biasing for Data Communication and c) Mach-Zender Modulator Biasing for Data Communication

### **Typical Performance**

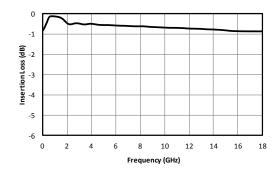


Fig. 2. RF insertion loss.

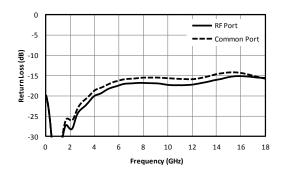


Fig. 3. Return loss.



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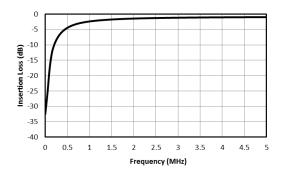


Fig. 4. Low frequency RF response.

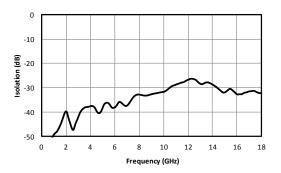


Fig. 6. DC-RF isolation.

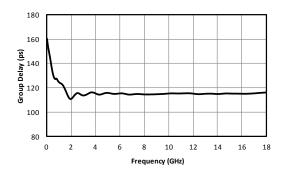


Fig. 8. Group delay.

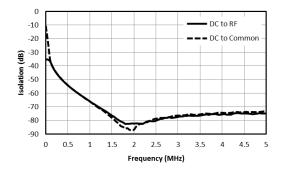


Fig. 5. Low frequency isolation.

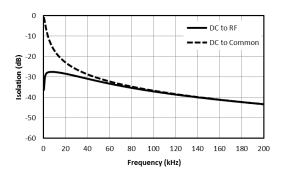


Fig. 7. Near DC isolation

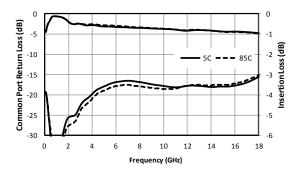


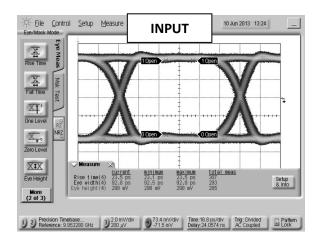
Fig. 9. Performance over temperature



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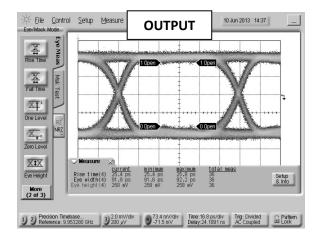


Fig. 10. Oscilloscope measurements of the BTN1-0018 with a 10Gb/s PRBS pattern. Eye diagrams are taken with a 2<sup>31</sup>-1 PRBS input demonstrating minimal eye distortion/closure afforded by the extremely low frequency operation of the bias tee.

Model Number	Description		
BTN1-0018	500 kHz to 18 GHz High Power Bias Tee		
	with SMA connectors1, LEAD-FREE/RoHS COMPLIANT		

<sup>&</sup>lt;sup>1</sup>Consult factory for other connector options.

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### **Revision History**

Revision c	ode	Revision Date	Comment
В		May 2020	RoHS Compliant Assembly